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P. Murugapandiyan, S. Ravimaran, J. William

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DC and Microwave Characteristics of Lg 50nm T-Gate InAlN/AlN/GaN HEMT for Future High Power RF Applications

P.Murugapandiyan^a , S.Ravimaran^b , J.William^c

^aAssistant Professor, Department of Electronics and Communication Engineering, Ariyalur Engineering college ,Melakaruppur,Tamilnadu-India.

^bProfessor, Department of Electrical and Computer Science, M.A.M College of Engineering, Trichy-India.

^cProfessor, Department of Electronics and Communication Engineering, M.A.M College of Engineering and Technology, Trichy-India.

E-mail: murugavlsi@gmail.com

Authors



P.Murugapandiyan has received his B.E in Electronics and Communication Engineering from Anna University , Chennai, Tamil Nadu, India in 2008 and he received Master of Engineering in VLSI Design from Anna University, Chennai, Tamil Nadu, India in the year 2013. He is pursuing Ph.D at Anna University, Chennai, Tamilnadu- India. Now he is working as Assistant Professor in the Department of Electronics and Communication Engineering, Ariyalur Engineering College Melakaruppur, Tamilnadu - India. His research focuses on modelling and simulation of III-N compound semiconductor materials and devices for future high speed with high power MMIC applications.



S.Ravimaran , Principal and Professor in Computer Science and Electrical Engineering department of the M.A.M. College of Engineering, Tamil Nadu,India and he has received his B.E. in computer science and engineering from National Institute of Technology, Tiruchirapalli, India in 1997 and his M.E. Computer science and engineering from Anna University, Chennai, Tamil Nadu, India in 2004. He has done his Ph.D. in Data and Transaction Management Using Surrogate Objects in Distributed Mobile Systems from Anna University Chennai, India in 2013. His research interests are High speed wireless Communication Networks and wide band antenna design for MMIC RF applications.

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